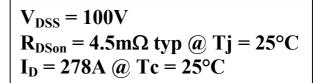
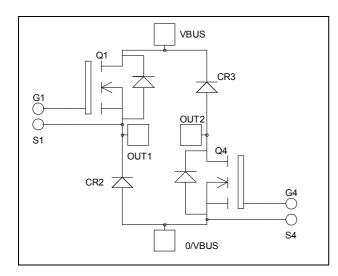
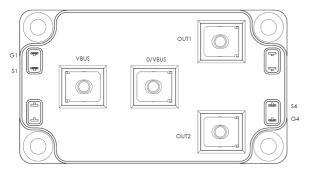


Asymmetrical - Bridge MOSFET Power Module







Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS V® MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage	100	V	
I_D	Continuous Drain Current	$T_c = 25$ °C	278	
ъ	Continuous Diani Current	$T_c = 80$ °C	207	A
I_{DM}	Pulsed Drain current	1100		
V_{GS}	Gate - Source Voltage	±30	V	
R _{DSon}	Drain - Source ON Resistance		5	mΩ
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	780	W
I_{AR}	Avalanche current (repetitive and non repetitive)		100	A
E_{AR}	Repetitive Avalanche Energy		50	m I
E_{AS}	Single Pulse Avalanche Energy		3000	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$	$T_j = 25$ °C			200	^	
		$V_{GS} = 0V, V_{DS} = 80V$	$T_j = 125$ °C			1000	μΑ	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 125A$			4.5	5	mΩ	
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$		2		4	V	
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$	V			±200	nA	

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		20		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		8		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		2.9		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		700		
Q_{gs}	Gate – Source Charge	$V_{\text{Bus}} = 50V$		120		nC
Q_{gd}	Gate – Drain Charge	$I_D = 250A$		360		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		80		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$ $V_{Bus} = 66V$		165		
$T_{d(off)}$	Turn-off Delay Time	$I_{\rm D} = 250 A$		280		ns
T_{f}	Fall Time	$R_G = 2.5 \Omega$		135		
E_{on}	Turn-on Switching Energy	Inductive switching @ 25°C		1.1		ma I
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 250A, R_G = 2.5\Omega$		1.2		mJ
E_{on}	Turn-on Switching Energy	Inductive switching @ 125°C		1.22		ma I
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 250A, R_G = 2.5\Omega$		1.28		mJ

Diode ratings and characteristics

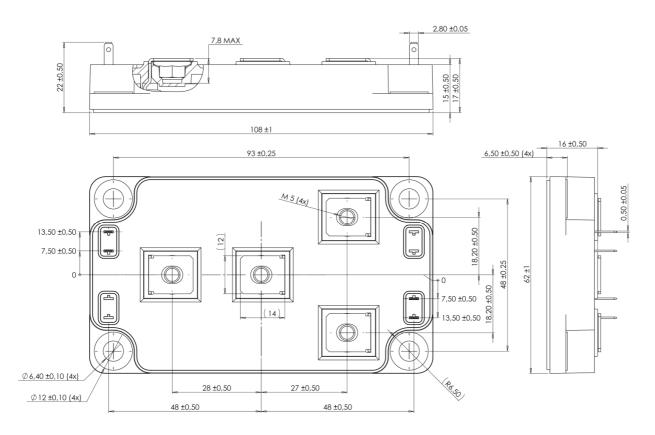
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			200			V
т	Maximum Reverse Leakage Current	V _R =200V	$T_j = 25^{\circ}C$			350	1
I_{RM}			$T_{j} = 125^{\circ}C$			600	μA
I_{F}	DC Forward Current		Tc = 80°C		200		A
	Diode Forward Voltage	$I_{\rm F} = 200 A$			1		
V_{F}		$I_F = 400A$			1.4		V
		$I_{\rm F} = 200 A$	$T_i = 125$ °C		0.9		
t_{rr}	Reverse Recovery Time	$I_F = 200A$ $V_R = 133V$	$T_j = 25$ °C		60		ns
·rr			$T_{j} = 125^{\circ}C$		110		113
Q _{rr}	Reverse Recovery Charge	$di/dt = 400 A/\mu s$ T_j	$T_j = 25$ °C		400		nC
			$T_{j} = 125^{\circ}C$		1680		iiC



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Liunction to Case Thermal Resistance		transistor			0.16	°C/W
			diode			0.29	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

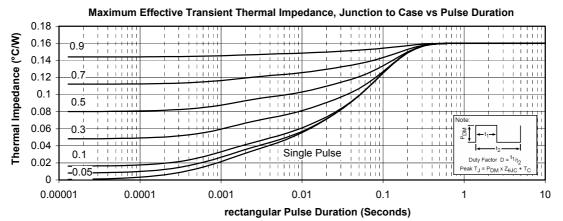
SP6 Package outline (dimensions in mm)

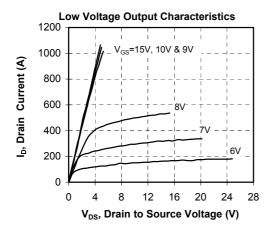


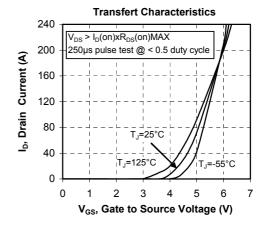
 $See \ application \ note \ APT0601 - Mounting \ Instructions \ for \ SP6 \ Power \ Modules \ on \ www.microsemi.com$

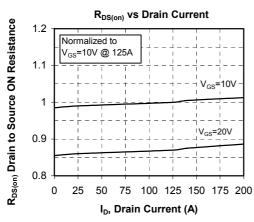


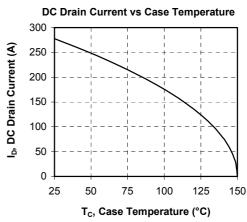
Typical Performance Curve



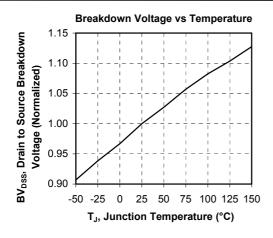


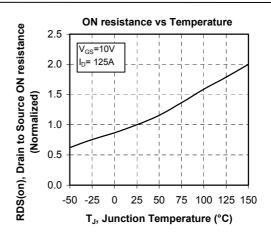


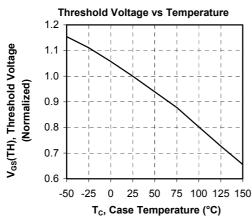


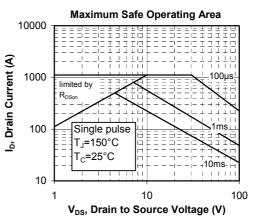


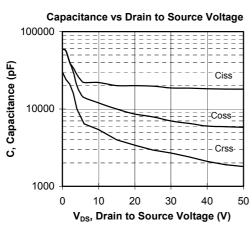


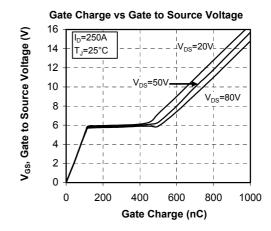




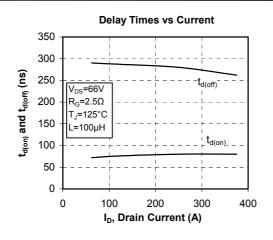


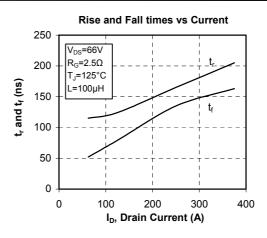


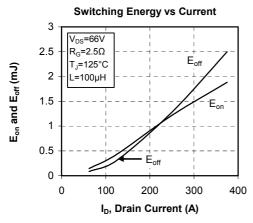


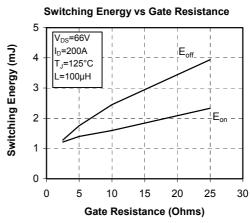


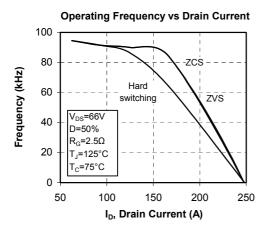


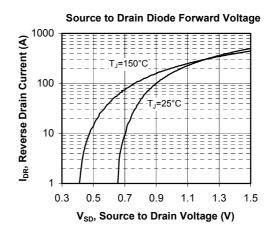














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